General Purpose Transistor

PNP Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|-----------------------------------|------------------|-------|------|
| Collector - Emitter Voltage | V _{CEO} | -40 | Vdc |
| Collector - Base Voltage | V _{CBO} | -40 | Vdc |
| Emitter-Base Voltage | V _{EBO} | -5.0 | Vdc |
| Collector Current – Continuous | Ic | -200 | mAdc |
| Collector Current – Peak (Note 3) | I _{CM} | -800 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|------------------------------------------------------------------------------------------------|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board (Note 1) @ T _A = 25°C Derate above 25°C | P _D | 225 1.8 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation Alumina Substrate, (Note 2) @ T _A = 25°C Derate above 25°C | P _D | 300 2.4 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -65 to +150 | °C |

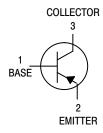
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.
- 3. Reference SOA curve.



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SOT-23 (TO-236) **CASE 318** STYLE 6

MARKING DIAGRAM



2A = Specific Device Code

= Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

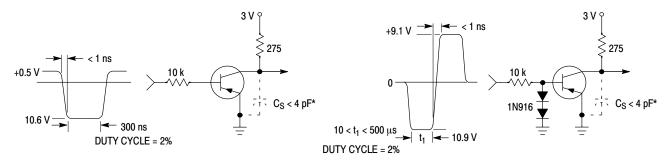
| Device | Package | Shipping [†] |
|---------------|---------------------|-------------------------|
| MMBT3906LT1G | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| MMBT3906LT3G | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |
| SMMBT3906LT1G | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| SMMBT3906LT3G | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Charac | Symbol | Min | Max | Unit | | |
|----------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------|----------------------|-----------------------------|--------------------|--------------------|--|
| OFF CHARACTERISTICS | | | | | | |
| Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mAdc}, I_B = 0)$ | V _{(BR)CEO} | -40 | _ | Vdc | | |
| Collector – Base Breakdown Voltage $(I_C = -10 \mu Adc, I_E = 0)$ | V _{(BR)CBO} | -40 | - | Vdc | | |
| Emitter – Base Breakdown Voltage $(I_E = -10 \mu Adc, I_C = 0)$ | | V _{(BR)EBO} | -5.0 | - | Vdc | |
| Base Cutoff Current ($V_{CE} = -30 \text{ Vdc}$, $V_{EB} = -3.0 \text{ Vdc}$) | | I _{BL} | - | -50 | nAdc | |
| Collector Cutoff Current (V _{CE} = -30 Vdc, V _{EB} = -3.0 Vdc) | | I _{CEX} | - | -50 | nAdc | |
| ON CHARACTERISTICS (Note 4) | | 1 | • | • | • | |
| DC Current Gain | | H _{FE} | 60 80 100 60 30 | - 300 - - | - | |
| Collector – Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}$, $I_B = -1.0 \text{ mAdc}$) ($I_C = -50 \text{ mAdc}$, $I_B = -5.0 \text{ mAdc}$) | V _{CE(sat)} | _ _ | -0.25 -0.4 | Vdc | | |
| Base-Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc) | V _{BE(sat)} | -0.65 - | -0.85 -0.95 | Vdc | | |
| SMALL-SIGNAL CHARACTERISTICS | | | | | | |
| Current-Gain - Bandwidth Product (I _C = -10 mAdc, V _{CE} = -20 Vdc, f | = 100 MHz) | f _T | 250 | - | MHz | |
| Output Capacitance $(V_{CB} = -5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ M})$ | C _{obo} | - | 4.5 | pF | | |
| Input Capacitance ($V_{EB} = -0.5 \text{ Vdc}$, $I_C = 0$, $f = 1.0 \text{ M}$ | C _{ibo} | - | 10 | pF | | |
| Input Impedance ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, | f = 1.0 kHz) | h _{ie} | 2.0 | 12 | kΩ | |
| Voltage Feedback Ratio ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, | f = 1.0 kHz) | h _{re} | 0.1 | 10 | X 10 ⁻⁴ | |
| Small – Signal Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, | h _{fe} | 100 | 400 | - | | |
| Output Admittance ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, | h _{oe} | 3.0 | 60 | μmhos | | |
| Noise Figure (I _C = $-100 \mu Adc$, V _{CE} = $-5.0 Vdc$, | NF | - | 4.0 | dB | | |
| SWITCHING CHARACTERISTICS | | • | • | • | • | |
| Delay Time | $(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc},$ | t _d | _ | 35 | no | |
| Rise Time | $I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$ | t _r | - | 35 | ns | |
| Storage Time | $(V_{CC} = -3.0 \text{ Vdc}, I_{C} = -10 \text{ mAdc},$ | t _s | _ | 225 | ns | |
| Fall Time | $I_{B1} = I_{B2} = -1.0 \text{ mAdc}$ | t _f | _ | 75 | 1.5 | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width $\leq 300~\mu s$, Duty Cycle $\leq 2.0\%$.

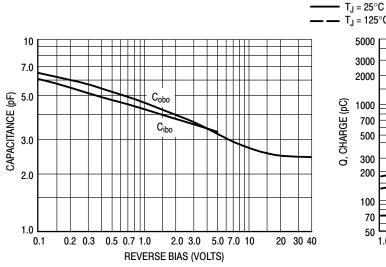


* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

Figure 2. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS





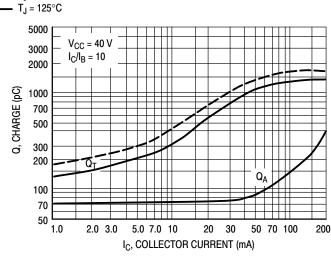


Figure 4. Charge Data

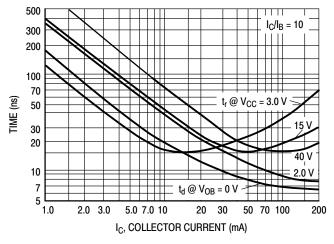


Figure 5. Turn-On Time

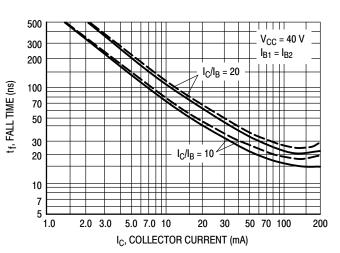
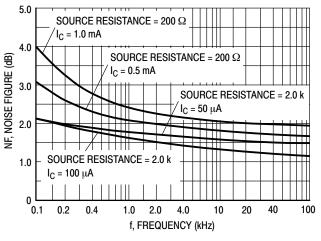


Figure 6. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



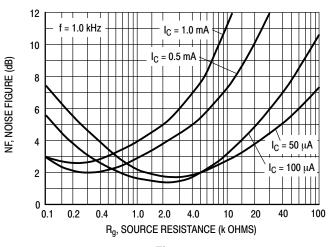
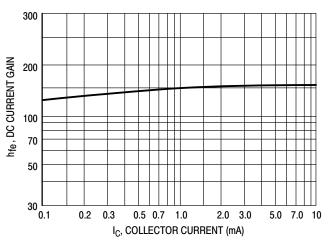


Figure 7.

Figure 8.

h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



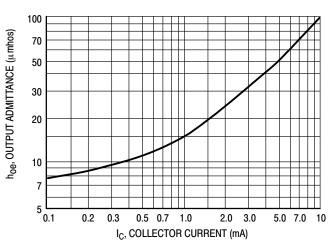
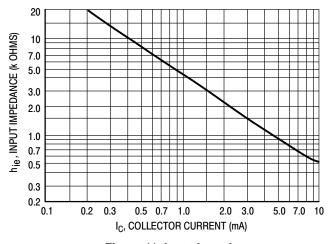


Figure 9. Current Gain

Figure 10. Output Admittance



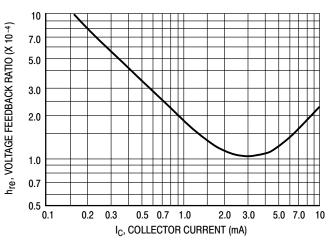


Figure 11. Input Impedance

Figure 12. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

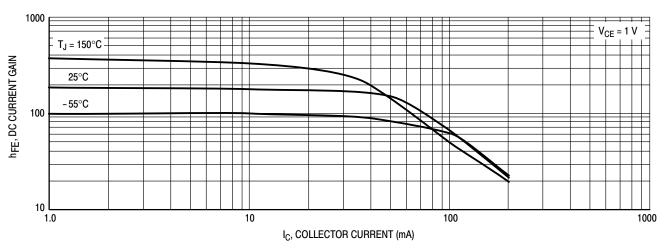


Figure 13. DC Current Gain

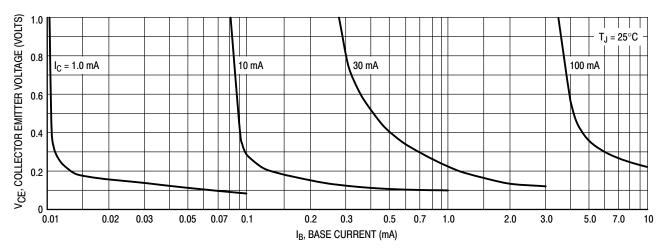


Figure 14. Collector Saturation Region

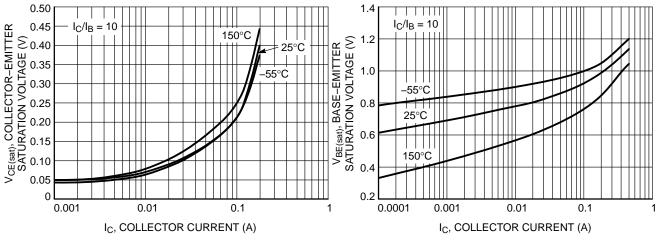


Figure 15. Collector Emitter Saturation Voltage vs. Collector Current

Figure 16. Base Emitter Saturation Voltage vs.
Collector Current

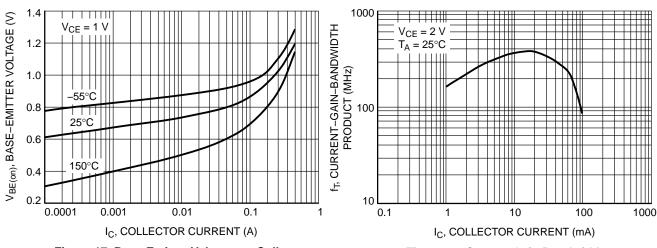


Figure 17. Base Emitter Voltage vs. Collector Current

Figure 18. Current Gain Bandwidth vs. Collector Current

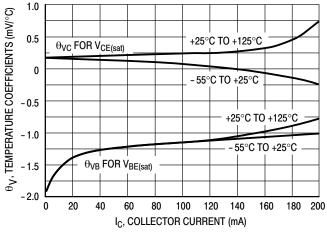


Figure 19. Temperature Coefficients

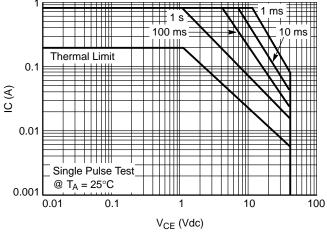


Figure 20. Safe Operating Area

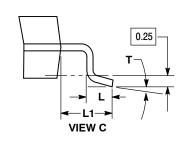


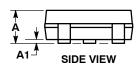
SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

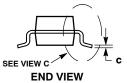
DATE 30 JAN 2018

SCALE 4:1 D

TOP VIEW







RECOMMENDED SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

3. ANODE

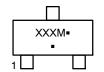
- 3X b

NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | INCHES | | | |
|-----|-------------|------|--------|-------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| С | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| е | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | 0° | | 10° | 0° | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | ı | |
|-------------------------------------------|-------------------------------------------------------|-------------------------------------------------------|------------------------------------------------------------|------------------|------------------|
| STYLE 9: | STYLE 10: | STYLE 11: | STYLE 12: | STYLE 13: | STYLE 14: |
| PIN 1. ANODE | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. SOURCE | PIN 1. CATHODE |
| 2. ANODE | 2. SOURCE | 2. CATHODE | 2. CATHODE | 2. DRAIN | 2. GATE |
| 3. CATHODE | 3. GATE | 3. CATHODE-ANODE | 3. ANODE | 3. GATE | 3. ANODE |
| STYLE 15: | STYLE 16: | STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE | STYLE 18: | STYLE 19: | STYLE 20: |
| PIN 1. GATE | PIN 1. ANODE | | PIN 1. NO CONNECTION | I PIN 1. CATHODE | PIN 1. CATHODE |
| 2. CATHODE | 2. CATHODE | | 2. CATHODE | 2. ANODE | 2. ANODE |
| 3. ANODE | 3. CATHODE | | 3. ANODE | 3. CATHODE-ANODE | 3. GATE |
| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| 2. SOURCE | 2. OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |
| 3. DRAIN | 3. INPUT | 3. CATHODE | 3. SOURCE | 3. GATE | 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE | | | | |

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|------------------|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| DESCRIPTION: | SOT-23 (TO-236) | | PAGE 1 OF 1 |

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